

UHF Variable Capacitance Diode

FEATURES

- Excellent linearity
- Very small plastic SMD package.
- C28: 1.9 pF; ratio: 10
- Low series resistance.

APPLICATIONS

- Electronic tuning in UHF television tuners.
- Radio upconversion concepts
- VCO.

DESCRIPTION

The BB135 is a variable capacitance diode, fabricated in planar technology, and encapsulated in the SOD323 very small plastic SMD package.

The matched type, BB134 has the same specification.



BB135



SOD-323

MARKING DIAGRAM



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V_R	continuous reverse voltage	–	30	V
I_F	continuous forward current	–	20	mA
T_{stg}	storage temperature	–55	+150	°C
T_j	operating junction temperature	–55	+125	°C

ELECTRICAL CHARACTERISTICS

$T_j = 25\text{ °C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_R	reverse current	$V_R = 30\text{ V}$; see Fig.2	–	10	nA
		$V_R = 30\text{ V}$; $T_j = 85\text{ °C}$; see Fig.2	–	200	nA
r_s	diode series resistance	$f = 470\text{ MHz}$; note 1	–	0.75	Ω
C_d	diode capacitance	$V_R = 0.5\text{ V}$; $f = 1\text{ MHz}$; see Figs 1 and 3	17.5	21	pF
		$V_R = 28\text{ V}$; $f = 1\text{ MHz}$; see Figs 1 and 3	1.7	2.1	pF
$\frac{C_d(0.5V)}{C_d(28V)}$	capacitance ratio	$f = 1\text{ MHz}$	8.9	12	

Note

1. V_R is the value at which $C_d = 9\text{ pF}$.

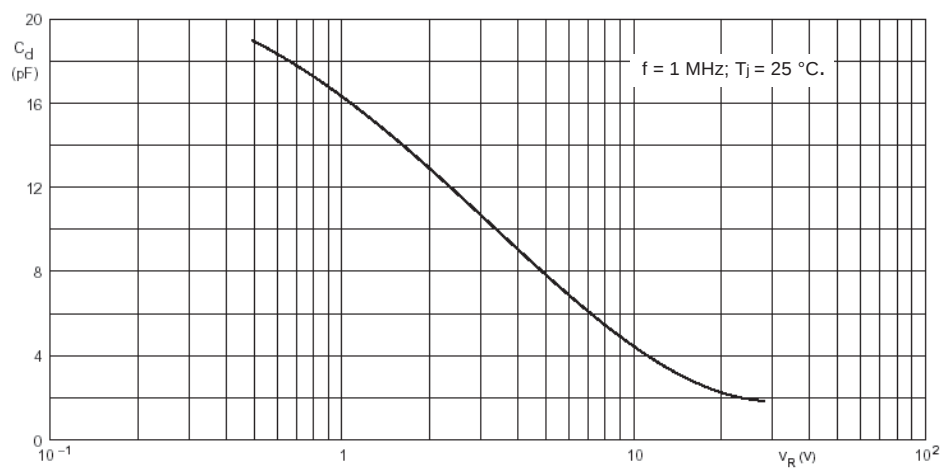
BB135


Fig.1 Diode capacitance as a function of reverse voltage; typical values.

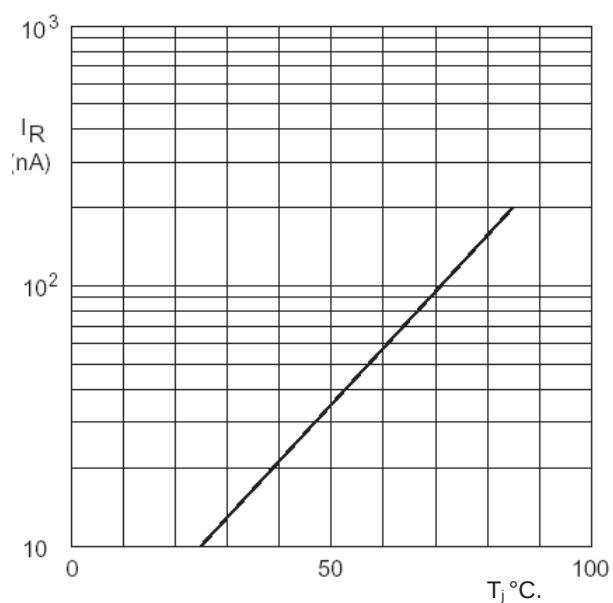


Fig.2 Reverse current as a function of junction temperature; maximum values.

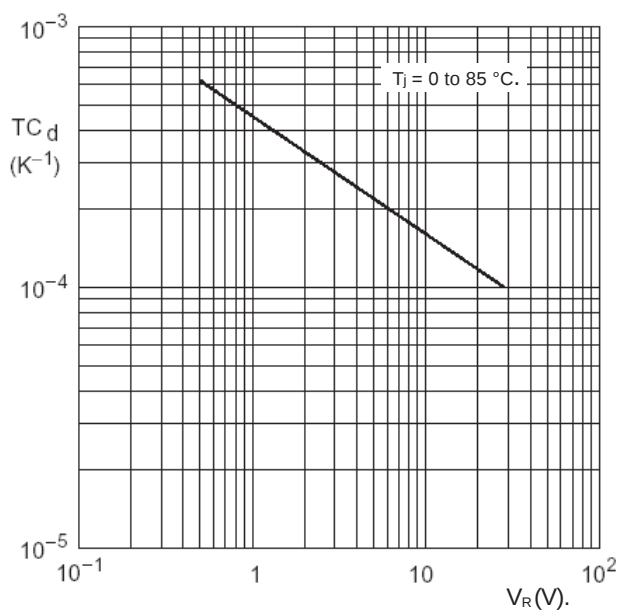


Fig.3 Temperature coefficient of diode capacitance as a function of reverse voltage; typical values.